

STC403Q

NPN Silicon Transistor

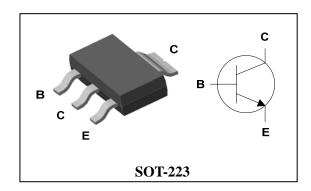
Applications

- Power amplifier application
- High current switching application

Features

- Power transistor General Purpose application
- Low saturation voltage
- : $V_{CE(sat)}=0.4V(Typ.)$
- High Voltage: VCEO= 60V Min

PIN Connection



Ordering Information

Type No.	Marking	Package Code
STC403Q	STC403□	SOT-223

□ : Year & Week Code

Absolute Maximum Ratings

[Ta=25°C]

10001444 1/1441114111 1144115			[14 20 0]
Characteristic	Symbol	Rating	Unit
Collector-Base voltage	V_{CBO}	80	V
Collector-Emitter voltage	V _{CEO}	60	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	I_{C}	3	A(DC)
Collector current	I _{CP} *	6	A(Pulse)
Collector Dower dissination	P _C	1.1	W
Collector Power dissipation	P _C ** 1.5		VV
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55~150	°C

^{*:} Single pulse, tp= 300 μ s

KSD-T5A002-002

^{**:} When mounted on ceramic substrate(250 mm2×0.8t)

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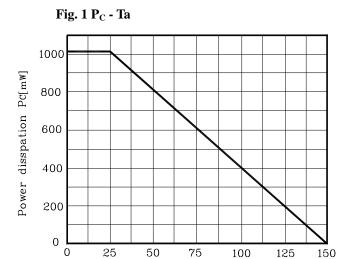
Electrical Characteristics

(Ta=25°C)

Charac	cteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Emitter breakdown voltage		BV _{CEO}	I _C =50mA, I _B =0	60	-	-	V
Collector cut-off current		I_{CBO}	V _{CB} =60V, I _E =0	-	-	50	μА
Emitter cut-off current		I_{EBO}	V _{EB} =5V, I _C =0	-	-	50	μА
DC current gain		h _{FE} *	V _{CE} =5V, I _C =0.5A	200	-	400	-
Base-Emitter on voltage		V _{BE(ON)}	V _{CE} =5V, I _C =0.5A	-	0.7	1	V
Collector-Emitter saturation voltage		$V_{CE(sat)}$	I _C =2A, I _B =0.2A	-	0.4	1	V
Transition frequency		f _T	V _{CB} =5V, I _C =0.5A	-	30	-	MHz
Collector output capacitance		C _{ob}	V _{CB} =10V, I _E =0, f=1MHz	-	35	-	pF
Switching Time	Turn-on Time	t _{on}	$\begin{array}{c c} & & & & & & & & \\ \hline & & & & & & & \\ \hline & & & &$	-	0.65	-	
	Storage Time	t _{stg}		-	1.3	-	μs
	Fall Time	t _f		-	0.65	-	

^{*} hFE rank : 200~400 Only

Electrical Characteristic Curves



Ambient temperature Ta[°C]

Fig. 3 h_{FE}.I_C

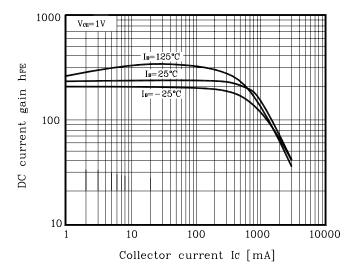


Fig. 5 I_C - V_{CE}

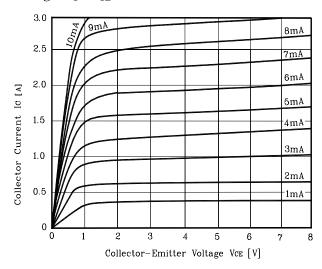


Fig. 2 V_{CE} - I_{C}

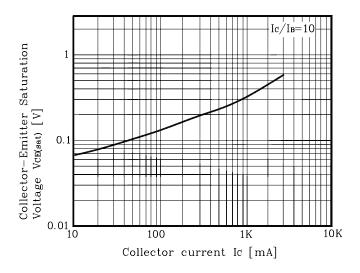


Fig. 4 h_{FE}.I_C

150

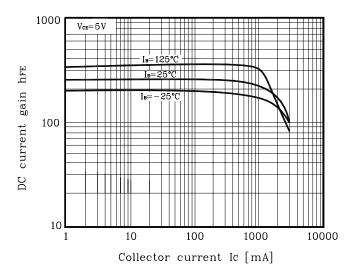
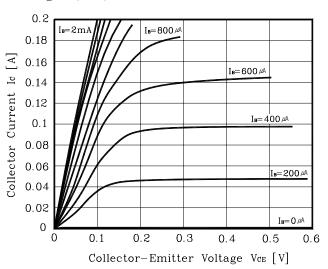


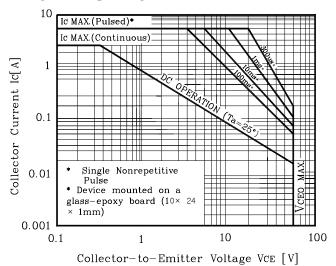
Fig. 6 I_C - V_{CE}



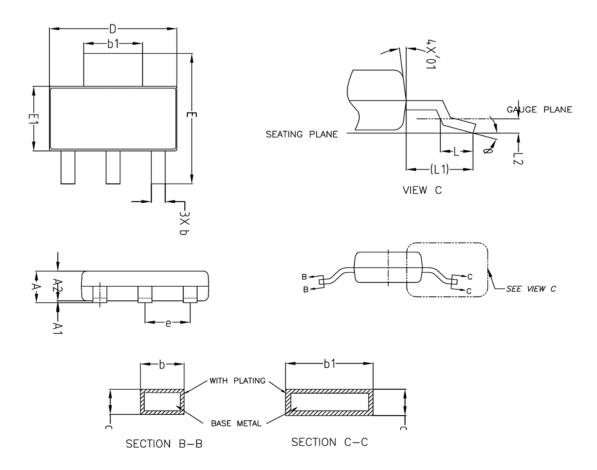
3

Electrical Characteristic Curves

Fig. 7 Safe operating Area

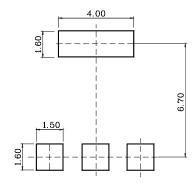


Outline Dimension



	MILLIMETERS			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	INOIE
Α	_	_	1.80	
A1	0.00	_	0.10	
A2	1.60	1.65	1.70	
Ь	0.68	_	0.76	
Ь1	2.95	_	3.07	
С	0.23	_	0.28	
D	6.40	6.50	6.60	
Ε	6.80	7.00	7.20	
E1	3.40	3.50	3.60	
е		2.30 BSC		
L	0.45	_	0.65	
L1		1.75 REF		
L2		0.10 BSC		
Ф	0,	_	10°	
0 1	5*	_	10°	

* Recommend PCB solder land [Unit: mm]



KSD-T5A002-002

5

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KSD-T5A002-002

6